

LCQ90510S5-N/M/P

InGaAs Laser Diode

Jun.2004. Ver. 0

◆ OVERVIEW

LCQ 90510S5-Serie is a MOCVD grown 905nm band *InGaAs* laser diode with quantum well structure. It's an attractive light source, with a typical light output power of 10mW for Laser, industrial optical module and sensor application

◆ APPLICATION

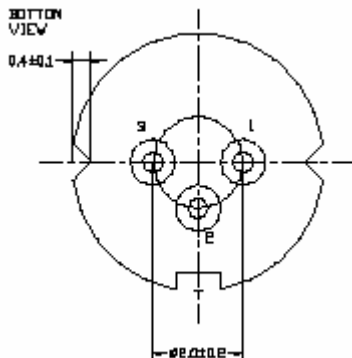
- Sensor

◆ FEATURES

- Visible Light Output : $\lambda_p = 905 \text{ nm}$
- Optical Power Output : 10mW CW
- Package Type : TO-18 (5.6mm ϕ)
- Built-in Photo Diode for Monitoring Laser Diode

◆ ELECTRICAL CONNECTION

Bottom View



Pin Configuration

N	LD anode= PD cathode (Fig. 1)
M	LD cathode= PD cathode (Fig. 2)
P	LD cathode= PD anode (Fig. 3)

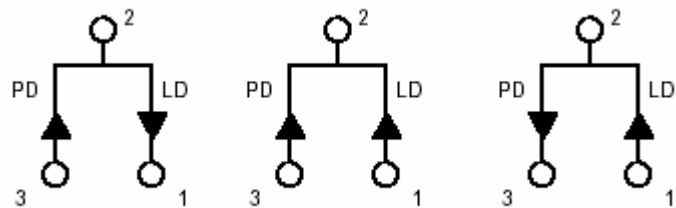


Fig. 1

LCQ90510S5N

Fig. 2

LCQ90510S5M

Fig. 3

LCQ90510S5P

◆ **ABSOLUTE MAXIMUM RATING at Tc=25°C**

Items	Symbols	Values	Unit
Optical Output Power	P	12	mW
Laser Diode Reverse Voltage	V	2	V
Photo Diode Reverse Voltage	V	30	V
Operating Temperature	Topr	-10 ~ +70	°C
Storage Temperature	Tstg	-40 ~ +85	°C

◆ **ELECTRICAL and OPTICAL CHARACTERISTICS at Tc=25°C**

Items	Symbols	Min.	Typ.	Max.	Unit	Condition
Optical Output Power	Po	-	10	-	mW	-
Threshold Current	Ith	-	15	25	mA	-
Operating Current	Iop	-	40	60	mA	Po=10mW
Operating Voltage	Vop	1.6	2.0	2.5	V	Po=10mW
Slope Efficiency	SE	0.3	0.5	0.7	mW/mA	
Lasing Wavelength	λ_p	895	905	915	nm	Po=10mW
Beam Divergence	$\theta_{ }$	9	13	15	deg	Po=10mW
	θ_{\perp}	26	33	36	deg	Po=10mW
Beam Angle	$\Delta\theta_{ }$	-	-	±2.5	deg	Po=10mW
	$\Delta\theta_{\perp}$	-	-	±3.0	deg	Po=10mW
Monitor Current	Im	0.1	0.4	0.6	mA	Po=10mW
Optical Distance	$\Delta X, \Delta Y, \Delta Z$	-	-	60	μm	Po=10mW

NOTICE : LCQ90510S5N-N/M/P to be operated on APC

The above product specifications are subject to change without notice.

◆ PACKAGE DIMENSION

